

PATENT ASSIGNMENT

Electronic Version v1.1
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SUBMISSION TYPE:	NEW ASSIGNMENT
NATURE OF CONVEYANCE:	ASSIGNMENT
CONVEYING PARTY DATA	
Name	Execution Date
SanDisk Corporation	04/04/2011
RECEIVING PARTY DATA	
Name:	SanDisk Technologies Inc.
Street Address:	6900 North Dallas Parkway
Internal Address:	Two Legacy Town Center
City:	Plano
State/Country:	TEXAS
Postal Code:	75024
PROPERTY NUMBERS Total: 1	
Property Type	Number
Patent Number:	7301813
CORRESPONDENCE DATA	
Fax Number:	(408)801-8512
<i>Correspondence will be sent via US Mail when the fax attempt is unsuccessful.</i>	
Phone:	4088012863
Email:	simona.benjamin@sandisk.com
Correspondent Name:	SanDisk Corporation
Address Line 1:	601 Mccarthy Boulevard
Address Line 2:	Patent Department/Simona Benjamin
Address Line 4:	Milpitas, CALIFORNIA 95035
ATTORNEY DOCKET NUMBER:	SDK0604.002US
NAME OF SUBMITTER:	Simona Benjamin
Total Attachments: 5 source=Assignment 61#page1.tif source=Assignment 61#page2.tif source=Assignment 61#page3.tif source=Assignment 61#page4.tif source=Assignment 61#page5.tif	

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ASSIGNMENT

WHEREAS, SanDisk Corporation, a Delaware corporation, doing business at 601 McCarthy Boulevard, Milpitas, CA 95035 (hereinafter referred to as **ASSIGNOR**), holds right, title and interest throughout the world in and to the patents and patent applications set forth in the attached Exhibit A, together with all divisions, continuations, or continuations-in-part thereof, and all patents issuing thereon including reissues, renewals, substitutions, re-examinations and extensions thereof, and any and all corresponding foreign patents and patent applications (hereinafter referred to as, collectively, **THE ASSIGNED PATENT RIGHTS**);

WHEREAS, SanDisk Technologies Inc., a Texas corporation, doing business at Two Legacy Town Center, 6900 North Dallas Parkway, Plano, Texas 75024, (hereinafter referred to as **ASSIGNEE**), is desirous of acquiring the full and exclusive right, title and interest in **THE ASSIGNED PATENT RIGHTS**;

NOW, THEREFORE, for good and valuable consideration, the receipt of which is hereby acknowledged, **ASSIGNOR** hereby assigns, transfers and conveys unto the said **ASSIGNEE**, and **ASSIGNEE** accepts, all of **ASSIGNOR**'s right, title and interest throughout the world in and to **THE ASSIGNED PATENT RIGHTS** and to all Letters Patent or applications or similar legal protection, not only in the United States and its territorial possessions, but in all countries foreign thereto to be obtained for **THE ASSIGNED PATENT RIGHTS**, and to any continuation, division, renewal, substitute or reissue thereof or any legal equivalent thereof in the United States or a foreign country for the full term or terms for which the same may be granted, including all priority rights under the International Convention; and **ASSIGNOR** hereby authorizes and requests the United States Commissioner of Patents and Trademarks and any officials of foreign countries whose duty it is to issue patents on applications as aforesaid, to issue all patents for **THE ASSIGNED PATENT RIGHTS** to **ASSIGNEE** in accordance with the terms of this **ASSIGNMENT** but subject to reserved rights including but not limited to those previously retained by, granted to, or owned by, the United States government, educational institutions or both and hereby transfers and conveys all rights of action, power and benefit belonging to or accruing from **THE ASSIGNED PATENT RIGHTS** including the right to undertake proceedings to recover past and future damages and claim all other relief in respect of any acts of infringement thereof whether such acts shall have been committed before or after the date of this assignment.

No other rights, immunities, or licenses, including, without limitation, any rights to any intellectual property owned, controlled or licensable by **ASSIGNOR** are granted or assigned to **ASSIGNEE** under this **ASSIGNMENT**, either expressly or by implication, estoppel, or otherwise, other than the rights expressly recited herein.

ASSIGNOR hereby covenants that no assignment, sale, agreement or encumbrance has been or will be made or entered into which would knowingly conflict with this Agreement;

ASSIGNOR further covenants that **ASSIGNEE** will, upon its lawful request, reasonably be provided with all pertinent facts and documents relating to **THE ASSIGNED PATENT RIGHTS** and legal equivalents as may be known and reasonably accessible to **ASSIGNOR** and that **ASSIGNOR** will testify as to the same in any administrative contest or litigation related thereto and will promptly execute and deliver to **ASSIGNEE** or its legal representative any and all papers, instruments or affidavits required to apply for, obtain, maintain, issue and enforce **THE ASSIGNED PATENT RIGHTS** and said equivalents in the United States or in any foreign country, which may be necessary or desirable to carry out the purposes thereof.

IN TESTIMONY WHEREOF, I hereunto set my hand as of the date indicated below.

SANDISK CORPORATION

Dated: 4th April 2011

Judy Bruner
Name: Judy Bruner
Title: EVP 2nd CFO

STATE OF California)
COUNTY OF Santa Clara) ss.

On this 4th day of April, 2011, before me Averil Branwen Watan (Notary Public), the undersigned Notary Public, personally appeared Judy Bruner,

who proved to me on the basis of satisfactory evidence to be the person(s) whose name(s) is/are subscribed to the within instrument and acknowledged to me that he/she/they executed the same in his/her/their authorized capacity(ies), and that by his/her/their signature(s) on the instrument the person(s), or the entity upon behalf of which the person(s) acted, executed the instrument.

I certify under PENALTY OF PERJURY under the laws of the State of California that the foregoing paragraph is true and correct.

WITNESS my hand and official seal.



Signature: Averil Watan
Signature of Notary Public

We accept the Assignment

SANDISK TECHNOLOGIES INC.

Dated: 4/4/11

James F. Brelsford
Name: James F. Brelsford
Title: President and Secretary

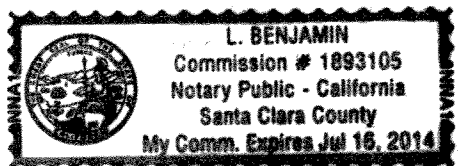
STATE OF California)
COUNTY OF Santa Clara) ss.

On this 4 day of April, 2011, before me L. Benjamin, the undersigned Notary Public, personally appeared JAMES F. BRELSFORD

who proved to me on the basis of satisfactory evidence to be the person(s) whose name(s) is/are subscribed to the within instrument and acknowledged to me that he/she/they executed the same in his/her/their authorized capacity(ies), and that by his/her/their signature(s) on the instrument the person(s), or the entity upon behalf of which the person(s) acted, executed the instrument.

I certify under PENALTY OF PERJURY under the laws of the State of California that the foregoing paragraph is true and correct.

WITNESS my hand and official seal.



Signature: L. Benjamin
Signature of Notary Public

Exhibit A

FILE #	INVENTORS	TITLE	COUNTRY	STATUS	SER #	FILING DATE	PAT #	ISSUE DATE
SDK0602.000US	Carlos J. Gonzalez, Daniel Guterman	Methods of cell population distribution assisted read margining	US	Issued	11535853	27-Sep-06	7886204	8-Feb-11
SDK0602.001US	Carlos J. Gonzalez, Daniel Guterman	Memory with cell population distribution assisted read margining	US	Issued	11535879	27-Sep-06	7716538	11-May-10
SDK0602.002US	Carlos J. Gonzalez, Daniel Guterman	Methods of cell population distribution assisted read margining	US	Pending	12984505	4-Jan-11		
SDK0603.000US	Kevin Conley, Yoram Cedar	Retargetable Memory Cell Redundancy Methods	US	Issued	11270198	8-Nov-05	7379330	27-May-08
SDK0603.001US	Kevin Conley, Yoram Cedar	Memory With Retargetable Memory Cell Redundancy	US	Issued	11270410	8-Nov-05	7447066	4-Nov-08
SDK0604.000US	Jian Chen	COMPENSATING FOR COUPLING DURING READ OPERATIONS ON NON-VOLATILE MEMORY	US	Issued	11099133	5-Apr-05	7196928	27-Mar-07
SDK0604.001US	Jian Chen	COMPENSATING FOR COUPLING DURING READ OPERATIONS ON NON-VOLATILE MEMORY	US	Issued	11616736	27-Dec-06	7301810	27-Nov-07
SDK0604.002US	Jian Chen	COMPENSATING FOR COUPLING DURING READ OPERATIONS ON NON-VOLATILE MEMORY	US	Issued	11616741	27-Dec-06	7301813	27-Nov-07
SDK0604.003US	Jian Chen	COMPENSATING FOR COUPLING DURING READ OPERATIONS ON NON-VOLATILE MEMORY	US	Issued	11616745	27-Dec-06	7315477	1-Jan-08
SDK0607.000US	Yan Li	Data Recovery Methods in Multi-State Memory After Program Fail	US	Issued	11304783	14-Dec-05	7345928	18-Mar-08
SDK0607.001US	Yan Li	Multi-State Memory Having Data Recovery After Program Fail	US	Issued	11304960	14-Dec-05	7420847	2-Sep-08
SDK0608.000US	Alan Welsh Sinclair	Logically-Addressed File Storage Methods	US	Issued	11302764	13-Dec-05	7877540	25-Jan-11
SDK0608.001US	Alan Welsh Sinclair	Logically-Addressed File Storage Systems	US	Published	11300568	13-Dec-05		
SDK0611.000US	Yan Li, Seungpil Lee, Siu Lung Chan	Non-volatile memory and method with power-saving read and program-verify operations	US	Issued	11083514	16-Mar-05	7251160	31-Jul-07
SDK0611.001US	Yan Li, Seungpil Lee, Siu Lung Chan	Non-volatile memory and method with power-saving read and program-verify operations	US	Allowed	11534297	22-Sep-06		
SDK0611.002US	Yan Li, Seungpil Lee, Siu Lung Chan	Non-volatile memory and method with power-saving read and program-verify operations	US	Issued	11534307	22-Sep-06	7570513	4-Aug-09
SDK0612.000US	Jian Chen	CONTINUED VERIFICATION IN NON-VOLATILE MEMORY WRITE OPERATIONS	US	Issued	11322011	29-Dec-05	7307887	11-Dec-07
SDK0612.001US	Jian Chen	SYSTEMS FOR CONTINUED VERIFICATION IN NON-VOLATILE MEMORY WRITE OPERATIONS	US	Issued	11322001	29-Dec-05	7352629	1-Apr-08
SDK0613.000US	Fabrice Jogand-Coulomb, Bahman Qawami, Farshid Sabet-Sharghi, Carlos J. Gonzalez	Portable Mass Storage Device with Virtual Machine Activation	US	Issued	11463256	8-Aug-06	7725614	25-May-10
SDK0613.002US	Fabrice Jogand-Coulomb, Bahman Qawami, Farshid Sabet-Sharghi, Carlos J. Gonzalez	Portable Mass Storage Device with Virtual Machine Activation	US	Pending	12762786	19-Apr-10		
SDK0617.000US	Jun Wan, Jeffrey Lutze, Masaaki Higashitani, Gerrit Jan Hemink, Ken Oowada, Jian Chen, Geoffrey S Gongwer	SELECTIVE APPLICATION OF PROGRAM INHIBIT SCHEMES IN NON-VOLATILE MEMORY	US	Issued	11127743	12-May-05	7295478	13-Nov-07
SDK0617.001US	Jun Wan, Jeffrey Lutze, Masaaki Higashitani, Gerrit Jan Hemink, Ken Oowada, Jian Chen, Geoffrey S Gongwer	SELECTIVE PROGRAM VOLTAGE RAMP RATES IN NON-VOLATILE MEMORY	US	Issued	11866261	2-Oct-07	7447086	4-Nov-08